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2N7002P 60 V, 360 mA N-channel Trench MOSFET Rev. 02 — 29 July 2010

Product data sheet

Product profile 1.

1.1 General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

1.2 Features and benefits

- AEC-Q101 qualified
- Logic-level compatible

1.3 Applications

- High-speed line driver
- Low-side loadswitch

- Trench MOSFET technology
- Very fast switching
- Relay driver
- Switching circuits

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _{amb} = 25 °C		-	-	60	V
V _{GS}	gate-source voltage			-20	-	20	V
I _D	drain current	V_{GS} = 10 V; T_{amb} = 25 °C	<u>[1]</u>	-	-	360	mA
Static cha	racteristics						
R _{DSon}	drain-source on-state resistance	$ \begin{array}{l} V_{GS} = 10 \; V; \; I_D = 500 \; mA; \\ T_j = 25 \; ^\circC; \; pulsed; \; t_p \leq 300 \; \mus; \\ \delta \leq 0.01 \end{array} $		-	1	1.6	Ω
	Toeletanee	0 = 0.01					

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².



2. Pinning information

Table 2.	Pinning	j information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		-
2	S	source		
3	D	drain		G
			SOT23 (TO-236AB)	mbb076 S

3. Ordering information

Table 3. Ordering information				
Type number Package				
	Name	Description	Version	
2N7002P	TO-236AB	plastic surface-mounted package; 3 leads	SOT23	

4. Marking

Table 4.Marking codes

Type number	Marking code ^[1]
2N7002P	LW%

[1] % = -: made in Hong Kong; % = p: made in Hong Kong; % = t: made in Malaysia; % = W: made in China

5. Limiting values

Table 5. Limiting values

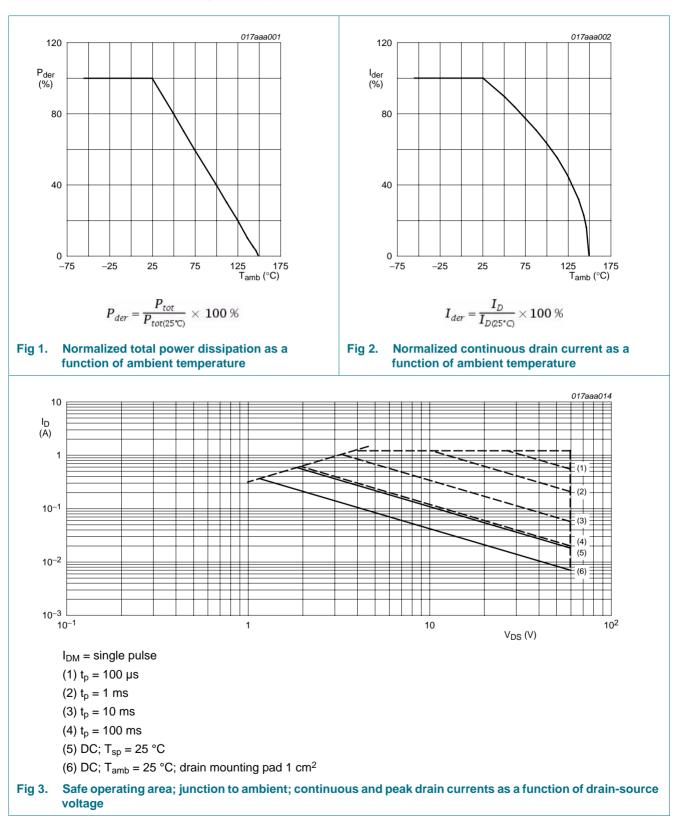
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _{amb} = 25 °C		-	60	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V_{GS} = 10 V; T_{amb} = 25 °C	<u>[1]</u>	-	360	mA
		$V_{GS} = 10 \text{ V}; \text{ T}_{amb} = 100 ^{\circ}\text{C}$	<u>[1]</u>	-	280	mA
I _{DM}	peak drain current	$T_{amb} = 25 \text{ °C}$; single pulse; $t_p \le 10 \mu\text{s}$		-	1.2	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	350	mW
			[1]	-	420	mW
		T _{sp} = 25 °C		-	1140	mW
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drai	in diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	360	mA

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

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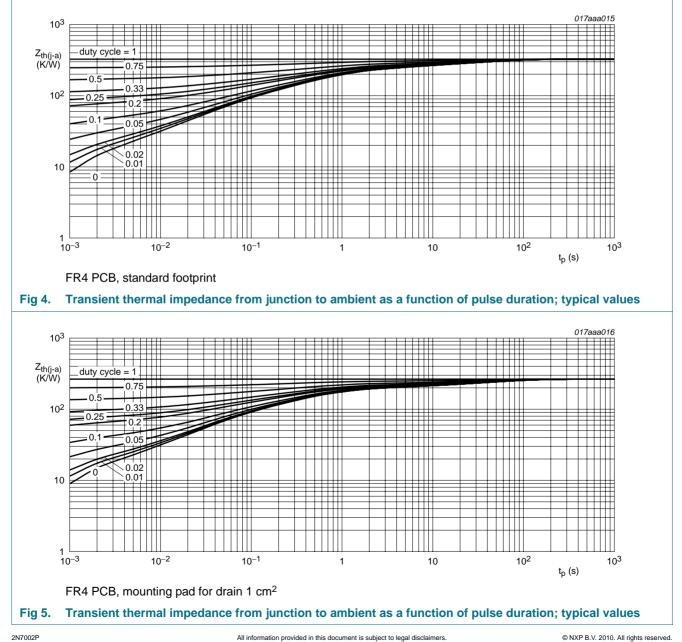
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 6.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance	in free air	[1]	-	310	370	K/W
	from junction to ambient		[2]	-	260	300	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	115	K/W

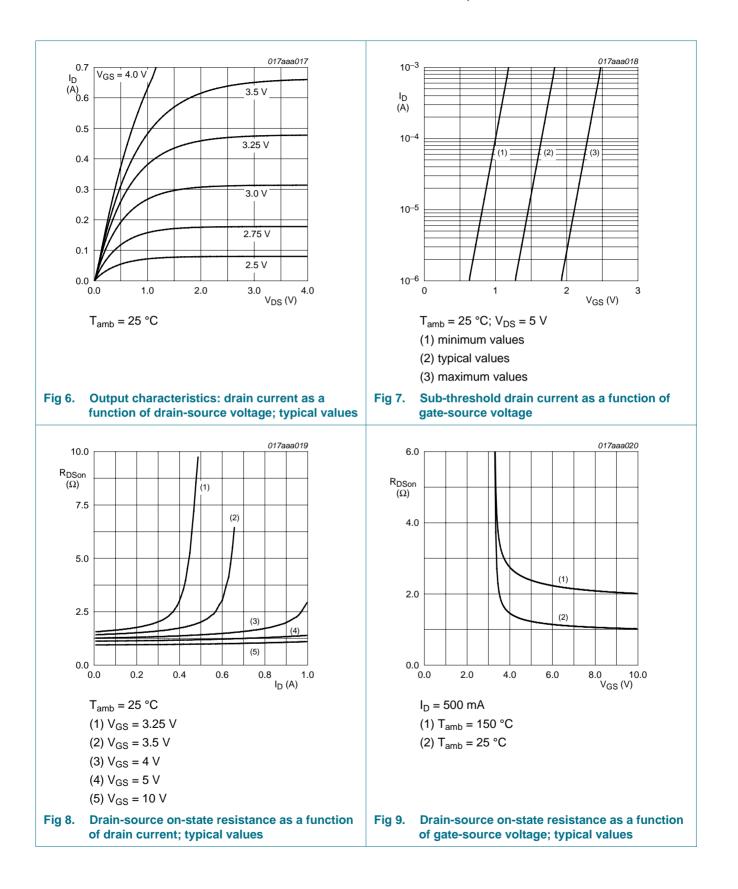
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

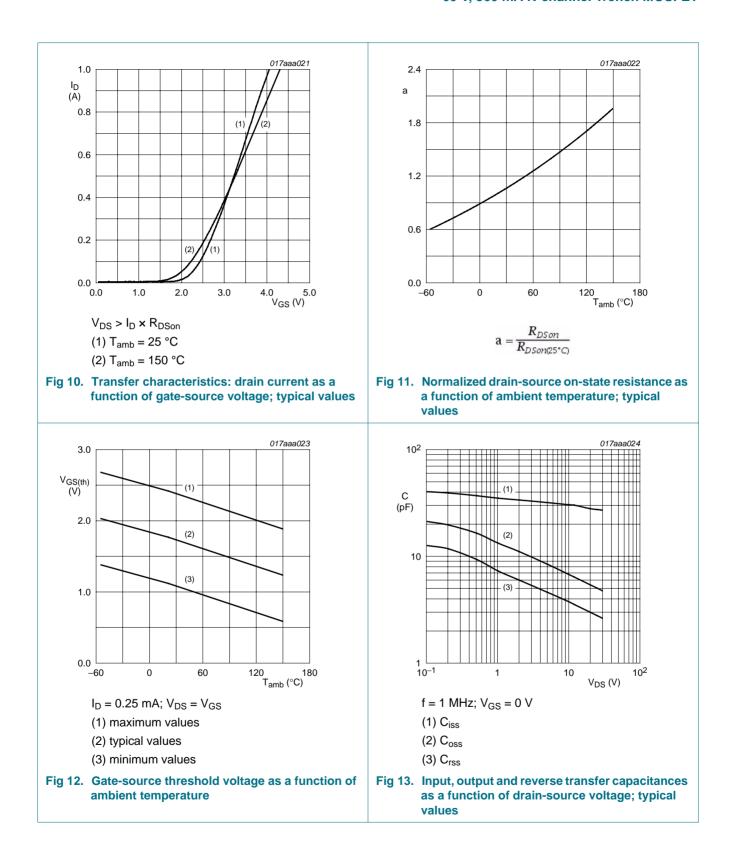
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².



7. Characteristics

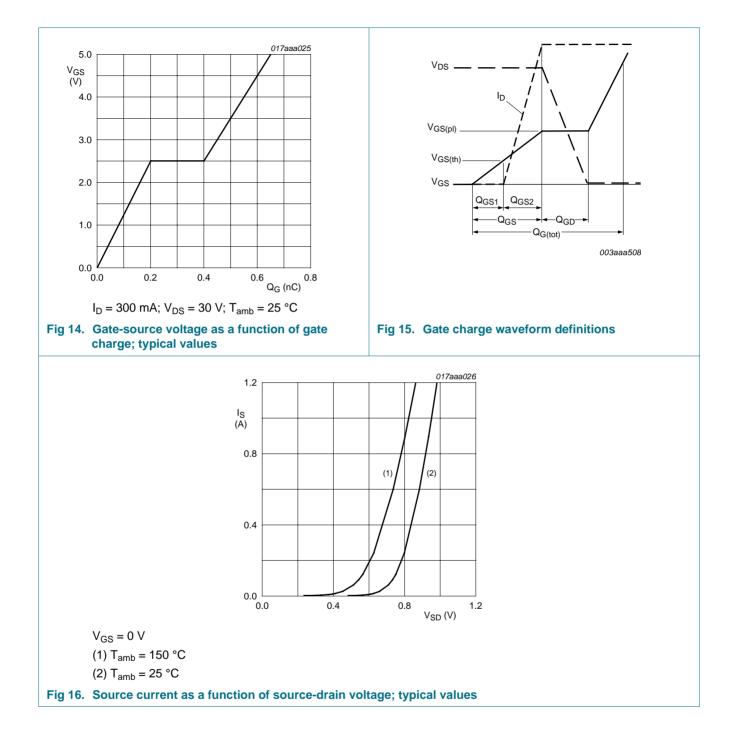
Table 7.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
V _{(BR)DSS}	drain-source breakdown voltage	$I_D = 10 \ \mu A; \ V_{GS} = 0 \ V; \ T_j = 25 \ ^\circ C$	60	-	-	V
V _{GSth}	gate-source threshold voltage	$I_D = 250 \ \mu\text{A}; \ V_{DS} = V_{GS}; \ T_j = 25 \ ^\circ\text{C}$	1.1	1.75	2.4	V
I _{DSS}	drain leakage current	$V_{DS} = 60 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	1	μA
		$V_{DS} = 60 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 150 \text{ °C}$	-	-	10	μA
I _{GSS}	gate leakage current	$V_{GS} = 20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	100	nA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	100	nA
R _{DSon} drain-source on-state resistance	drain-source on-state resistance	V_{GS} = 5 V; I _D = 50 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.01 ; T _j = 25 °C	-	1.3	2	Ω
		V_{GS} = 10 V; I _D = 500 mA; pulsed; t _p ≤ 300 µs; δ ≤ 0.01 ; T _j = 25 °C	-	1	1.6	Ω
g _{fs}	forward transconductance	V_{DS} = 10 V; I_D = 200 mA; pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.01$; T_j = 25 °C	-	400	-	mS
Dynamic	characteristics					
Q _{G(tot)}	total gate charge	$I_D = 300 \text{ mA}; V_{DS} = 30 \text{ V}; V_{GS} = 4.5 \text{ V};$	-	0.6	0.8	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.2	-	nC
Q_{GD}	gate-drain charge		-	0.2	-	nC
C _{iss}	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 10 \text{ V}; f = 1 \text{ MHz};$	-	30	50	pF
C _{oss}	output capacitance	$T_j = 25 \ ^{\circ}C$	-	7	-	pF
C _{rss}	reverse transfer capacitance		-	4	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 50 \text{ V}; \text{ R}_{L} = 250 \Omega; V_{GS} = 10 \text{ V}; \label{eq:VDS}$	-	3	6	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	4	-	ns
t _{d(off)}	turn-off delay time		-	10	20	ns
t _f	fall time		-	5	-	ns
Source-d	rain diode					
V _{SD}	source-drain voltage	I _S = 115 mA; V _{GS} = 0 V; T _i = 25 °C	0.47	0.75	1.1	V



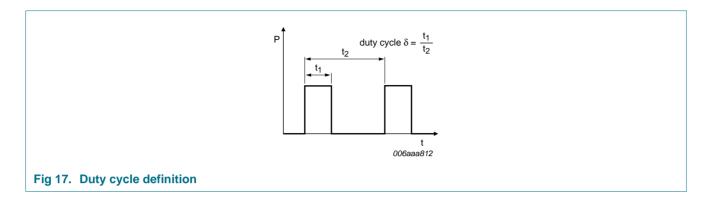


2N7002P

60 V, 360 mA N-channel Trench MOSFET

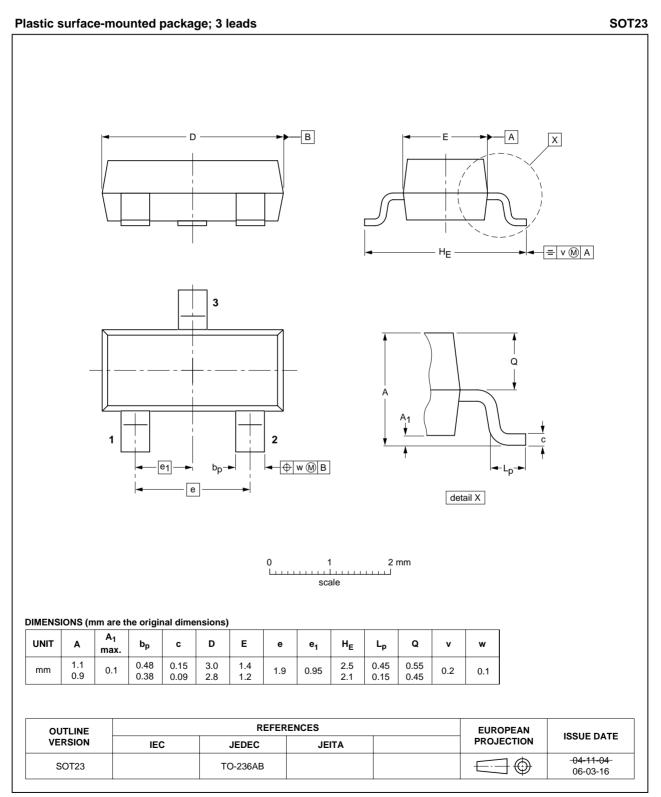


8. Test information

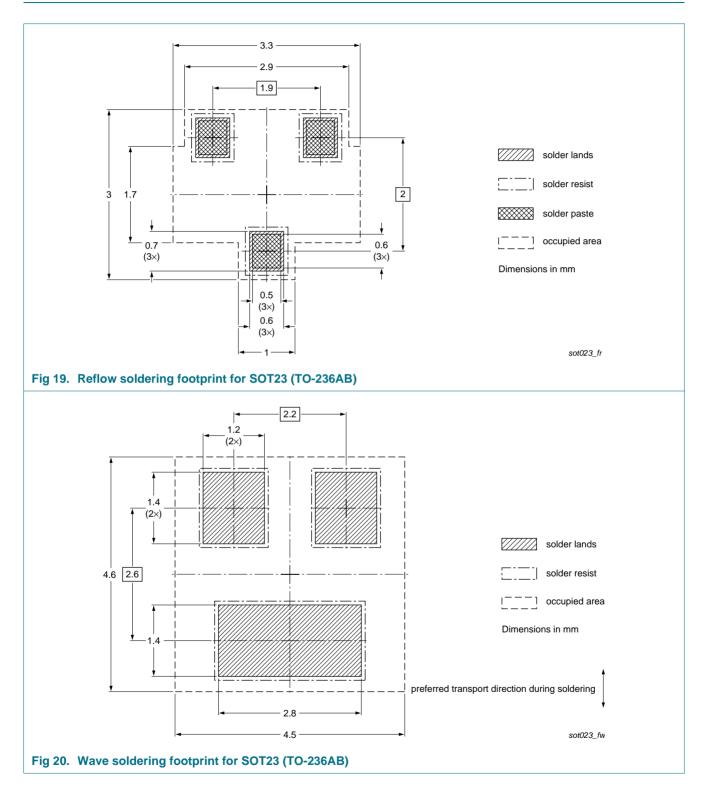


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9. Package outline



10. Soldering



11. Revision history

Table 8. Revi	sion history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
2N7002P v.2	20100729	Product data sheet	-	2N7002P_1
Modifications:	 Correction of the 	ermal values.		
	 Correction of value 	arious characteristics value	s including related gra	phs.
2N7002P_1	20100419	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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